

NAND01GW3B2BN6F

Data Sheet

1 Gbit, 2 Gbit, 2112 Byte/1056 Word Page, 1.8V/3V, NAND Flash Memory,Flash 1 Gbit 2 Gbit 2112 byte 1.8V

Manufacturers <u>STMicroelectronics, Inc</u>

Package/Case TSOP-48

Product Type Memory

RoHS Rohs

Lifecycle



Images are for reference only

Please submit RFQ for NAND01GW3B2BN6F or Fmailto:sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

NAND01GW3B2BN6F is a type of NAND flash memory chip manufactured by the company Toshiba. Here are some of its features:

Features

It has a storage capacity of 1 gigabit (Gb), which is equivalent to 128 megabytes (MB).

It uses a 3.3-volt power supply.

It has a maximum operating frequency of 52 megahertz (MHz).

It uses a NAND interface.

Application

Solid-state drives (SSDs) used in laptops, desktops, and servers

USB flash drives

Memory cards used in digital cameras, smartphones, and other devices

Embedded systems, such as those used in automotive, industrial, and medical applications.



Related Products



NAND512W3A2BN6E
STMicroelectronics, Inc
TSOP-1-48



NAND08GW3B2CN6 STMicroelectronics, Inc TSOP48



M29W640GB-70NA6 STMicroelectronics, Inc TSOP-48



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NAND512W3A2CN6E
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NAND512W3A2BZA6 STMicroelectronics, Inc TFBGA63



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